

NOT RECOMMENDED FOR NEW DESIGN **USE DMP2120U**



DMP2225L

P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)}	Package	I _D T _A = +25°C
-20V	110mΩ @ $V_{GS} = -4.5V$	SOT23	-2.6A
-200	225mΩ @ $V_{GS} = -2.5V$	30123	-2.0A

Description

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

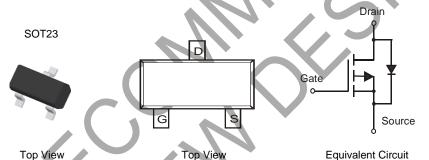
- General Purpose Interfacing Switch
- Power Management Functions

Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)



Ordering Information (Note 5)

Part Number	Qualification	Case	Packaging
DMP2225L-7	Standard	SOT-23	3000/Tape & Reel
DMP2225LQ-7	Automotive	SOT-23	3000/Tape & Reel

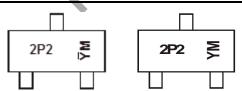
Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

Shanghai A/T Site

- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_grade_definitions/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



Chengdu A/T Site

2P2 = Product Type Marking Code

YM = Date Code Marking for SAT (Shanghai Assembly/ Test site) YM = Date Code Marking for CAT (Chengdu Assembly/ Test site) Y or \overline{Y} = Year (ex: E = 2017)

D

M = Month (ex: 9 = September)

Code

Date Code Key Year 2008 2009 2017 2018 2019 2020 2021 Code W Ε F G Η V Sep Month Feb Mar Apr Jul Aug Oct Dec Jan May Jun Nov



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Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V_{DSS}	-20	V
Gate-Source Voltage			V _{GSS}	±12	V
Continuous Drain Current (Note 6)	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-2.6 -2	А
Pulsed Drain Current (Note 7)			I _{DM}	8	Α

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 6)	P _D	1.08	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 6)	$R_{\theta JA}$	115	°C/W
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

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Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV _{DSS}	-20		_	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	I _{DSS}	_	_	-800	nA	$V_{DS} = -20V, V_{GS} = 0V$
On-State Drain Current	I _{D(ON)}	-6 -3			Α	$V_{DS} \le -5V$, $V_{GS} = -4.5V$ $V_{DS} \le -5V$, $V_{GS} = -2.5V$
Gate-Source Leakage	I _{GSS}	•	_	±80	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V _{GS(TH)}	-0.45		-1.25	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$
Static Drain-Source On-Resistance	R _{DS(ON)}	/	80	110	mΩ	$V_{GS} = -4.5V$, $I_D = -2.6A$
Static Drain-Source On-Resistance			165	225		$V_{GS} = -2.5V$, $I_D = -2.0A$
Forward Transfer Admittance	Y _{fs}		4		S	$V_{DS} = -5V, I_{D} = -2.6A$
Diode Forward Voltage (Note 7)	V_{SD}		_	-1.26	V	$V_{GS} = 0V, I_S = -2.6A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	C_{iss}		250	_	pF	101/11/101/11
Output Capacitance	Coss		88	_	pF $V_{DS} = -10V, V_{GS} = 0V$ $f = 1.0MHz$	
Reverse Transfer Capacitance	C _{rss}		58	_	pF	1 – 1.0101112
Gate Resistance	R_g		12	16	Ω	$V_{GS} = 0V$, $V_{DS} = 0V$, $f = 1MHz$
Total Gate Charge	Qg	_	4.3	5.3		$V_{GS} = -4.5V$, $V_{DS} = -10V$, $I_{D} = -2.7A$
Gate-Source Charge	Q_{gs}	_	0.9	_	nC	
Gate-Drain Charge	Q_{gd}	_	2.1	_		

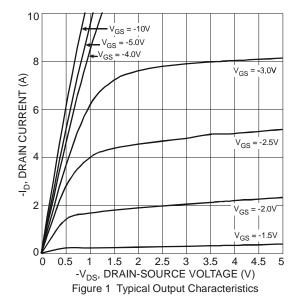
Notes:

- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 7. Repetitive rating, pulse width limited by junction temperature.
 8. Short duration pulse test used to minimize self-heating effect.
 9. Guaranteed by design. Not subject to production testing.



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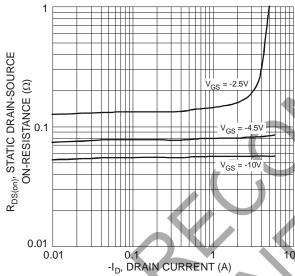


Figure 3 On-Resistance vs. Drain Current and Gate Voltage

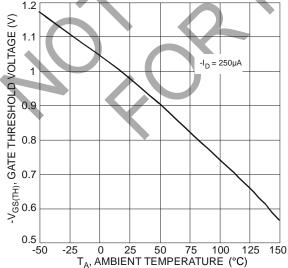
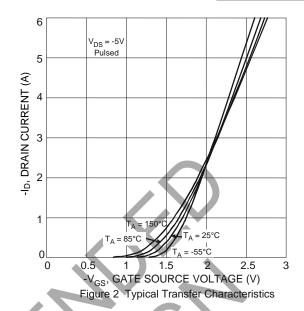
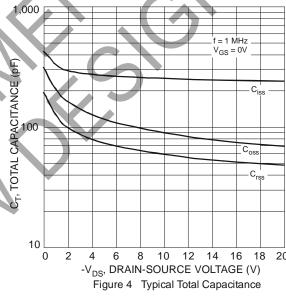


Figure 5 Gate Threshold Voltage vs. Ambient Temperature





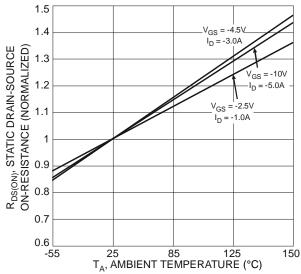


Figure 6 Normalized Static Drain-Source On-Resistance vs. Ambient Temperature



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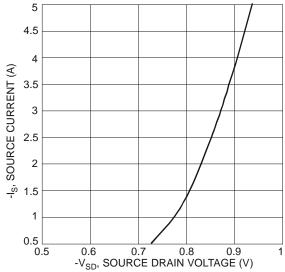
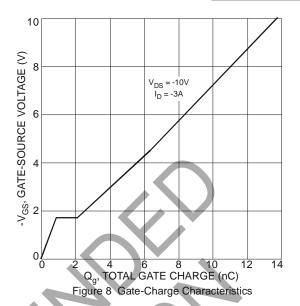
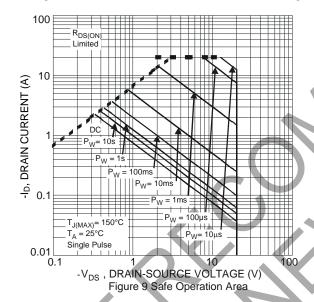
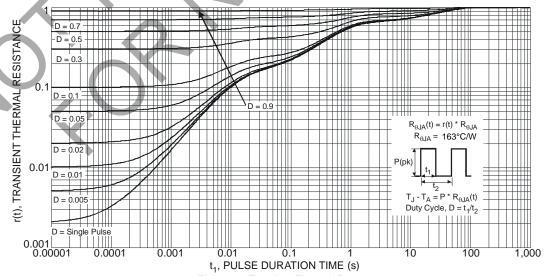


Figure 7 Reverse Drain Current vs. Source-Drain Voltage



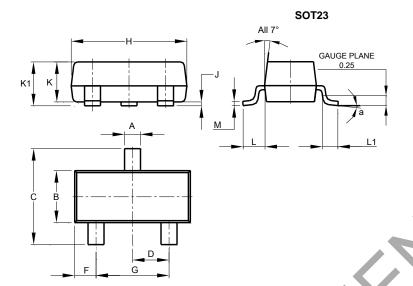






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

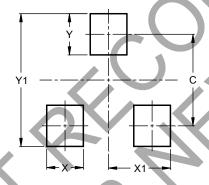


SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
L	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
M	0.085	0.150	0.110		
а	0°	8°			
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Υ	0.9
V1	2.0



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